NLAS5223C, NLAS5223CL

Ultra-Low 0.35 Ω Dual SPDT Analog Switch

The NLAS5223C is an advanced CMOS analog switch fabricated in Sub−micron silicon gate CMOS technology. The device is a dual Independent Single Pole Double Throw (SPDT) switch featuring Ultra−Low R_{ON} of 0.35 Ω, at V_{CC} = 4.3 V.

The part also features guaranteed Break Before Make (BBM) switching, assuring the switches never short the driver.

Features

- Ultra−Low R_{ON}, 0.35 Ω (typ) at V_{CC} = 4.3 V
- NLAS5223C Interfaces with 2.8 V Chipset
- NLAS5223CL Interfaces with 1.8 V Chipset
- Single Supply Operation from 1.65−4.5 V
- Full 0−V_{CC} Signal Handling Capability
- High Off−Channel Isolation
- Low Standby Current, < 50 nA
- Low Distortion
- R_{ON} Flatness of 0.15 Ω
- High Continuous Current Capability
  - ±320 mA Through Each Switch
- Large Current Clamping Diodes at Analog Inputs
  - ±320 mA Continuous Current Capability
- Package:
  - 1.4 x 1.8 x 0.55 mm UQFN10 Pb−Free
- These are Pb−Free Devices

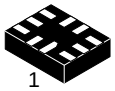
Applications

- Cell Phone Audio Block
- Speaker and Earphone Switching
- Ring−Tone Chip/Amplifier Switching
- Modems

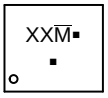
ON Semiconductor®

http://onsemi.com

MARKING DIAGRAM

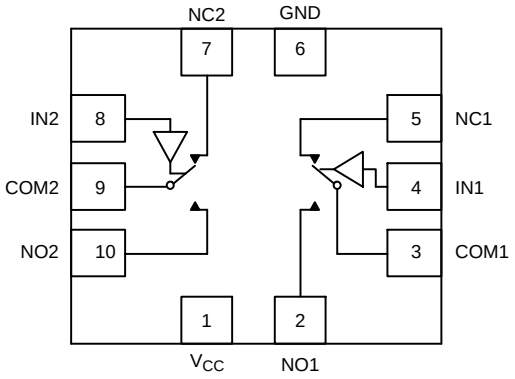


UQFN10
CASE 488AT



XX = Specific Device Code
M = Date Code/Assembly Location
▪ = Pb−Free Device

(Note: Microdot may be in either location)



FUNCTION TABLE

IN 1, 2	NO 1, 2	NC 1, 2
0	OFF	ON
1	ON	OFF

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 9 of this data sheet.

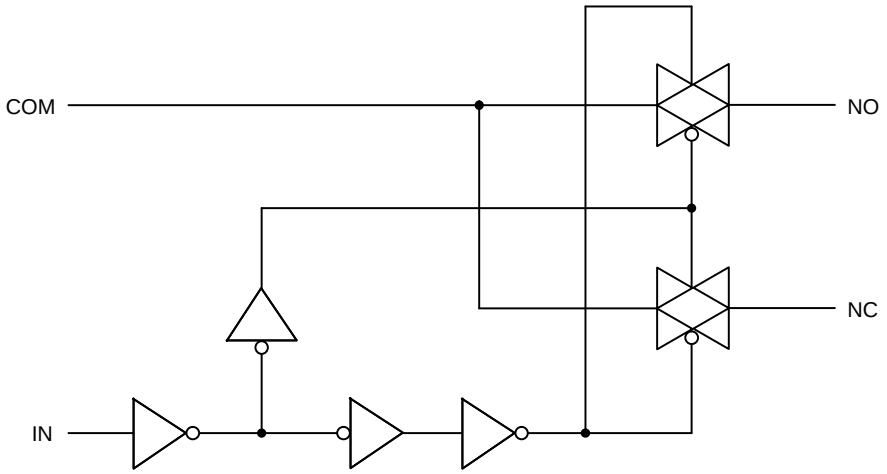


Figure 1. Logic Equivalent Circuit

PIN DESCRIPTION

QFN PIN #	Symbol	Name and Function
2, 5, 7, 10	NC1 to NC2, NO1 to NO2	Independent Channels
4, 8	IN1 and IN2	Controls
3, 9	COM1 and COM2	Common Channels
6	GND	Ground (V)
1	V_{CC}	Positive Supply Voltage

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Positive DC Supply Voltage	−0.5 to +7.0	V
V_{IS}	Analog Input Voltage (V_{NO}, V_{NC}, or V_{COM})	$-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V_{IN}	Digital Select Input Voltage	$-0.5 \le V_{IN} \le +5.5$	V
I_{anl1}	Continuous DC Current from COM to NC/NO	±320	mA
$I_{anl-pk1}$	Peak Current from COM to NC/NO, 10% Duty Cycle, 100 ms = t_{ON} (Note 1)	±600	mA
$I_{anl-pk2}$	Instantaneous Peak Current from COM to NC/NO, 10% Duty Cycle, t_{ON} < 1 μs	±850	mA
I_{clmp}	Continuous DC Current into COM/NO/NC with Respect to V_{CC} or GND	±100	mA
ESD	ESD Withstand Voltage Human Body Model (HBM)	>3000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Defined as 10% ON, 90% OFF Duty Cycle.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage	1.65	4.5	V
V_{IN}	Digital Select Input Voltage (OVT) Overvoltage Tolerance	GND	4.5	V
V_{IS}	Analog Input Voltage (NC, NO, COM)	GND	V_{CC}	V
T_A	Operating Temperature Range	−40	+85	°C
t_r, t_f	Input Rise or Fall Time, SELECT V_{CC} = 1.6 V − 2.7 V V_{CC} = 3.0 V − 4.5 V		 20 10	ns/V

NLAS5223C DC CHARACTERISTICS − DIGITAL SECTION (Voltages Referenced to GND)

Symbol	Parameter	Condition	V_{CC}	Guaranteed Limit		Unit
				25°C	−40°C to +85°C	
V_{IH}	Minimum High−Level Input Voltage, Select Inputs		3.0 4.3	1.4 2.0	1.4 2.0	V
V_{IL}	Maximum Low−Level Input Voltage, Select Inputs		3.0 4.3	0.7 0.8	0.7 0.8	V
I_{IN}	Maximum Input Leakage Current, Select Inputs	V_{IN} = V_{CC} or GND	4.3	±0.1	±1.0	μA
I_{OFF}	Power Off Leakage Current	V_{IN} = V_{CC} or GND	0	±0.5	±2.0	μA
I_{CC}	Maximum Quiescent Supply Current (Note 2)	Select and V_{IS} = V_{CC} or GND	1.65 to 4.5	±1.0	±2.0	μA

2. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

NLAS5223C DC ELECTRICAL CHARACTERISTICS − ANALOG SECTION

Symbol	Parameter	Condition	V_{CC}	Guaranteed Maximum Limit				Unit
				25°C		−40°C to +85°C		
				Min	Max	Min	Max	
R_{ON}	NC/NO On−Resistance (Note 3)	V_{IN} = V_{IL} or V_{IN} = V_{IH} V_{IS} = GND to V_{CC} I_{COM} = 100 mA	3.0 4.3		0.4 0.35		0.5 0.4	Ω
R_{FLAT}	NC/NO On−Resistance Flatness (Notes 3 and 4)	I_{COM} = 100 mA V_{IS} = 0 to V_{CC}	3.0 4.3		0.16 0.11		0.20 0.14	Ω
ΔR_{ON}	On−Resistance Match Between Channels (Notes 3 and 5)	V_{IS} = 1.5 V; I_{COM} = 100 mA V_{IS} = 2.2 V; I_{COM} = 100 mA	3.0 4.3		0.05 0.05		0.05 0.05	Ω
$I_{NC(OFF)}$ $I_{NO(OFF)}$	NC or NO Off Leakage Current (Note 3)	V_{IN} = V_{IL} or V_{IH} V_{NO} or V_{NC} = 0.3 V V_{COM} = 4.0 V	4.3	−5.0	5.0	−50	50	nA
$I_{COM(ON)}$	COM ON Leakage Current (Note 3)	V_{IN} = V_{IL} or V_{IH} V_{NO} 0.3 V or 4.0 V with V_{NC} floating or V_{NC} 0.3 V or 4.0 V with V_{NO} floating V_{COM} = 0.3 V or 4.0 V	4.3	−10	10	−100	100	nA

3. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
4. Flatness is defined as the difference between the maximum and minimum value of On−resistance as measured over the specified analog signal ranges.
5. ΔR_{ON} = $R_{ON(MAX)}$ − $R_{ON(MIN)}$ between NC1 and NC2 or between NO1 and NO2.

NLAS5223CL DC CHARACTERISTICS − DIGITAL SECTION (Voltages Referenced to GND)

Symbol	Parameter	Condition	V_{CC}	Guaranteed Limit		Unit
				25°C	−40°C to +85°C	
V_{IH}	Minimum High−Level Input Voltage, Select Inputs		3.0 4.3	1.3 1.6	1.3 1.6	V
V_{IL}	Maximum Low−Level Input Voltage, Select Inputs		3.0 4.3	0.5 0.6	0.5 0.6	V
I_{IN}	Maximum Input Leakage Current, Select Inputs	V_{IN} = 4.5 V or GND	4.3	±0.1	±1.0	μA
I_{OFF}	Power Off Leakage Current	V_{IN} = 4.5 V or GND	0	±0.5	±2.0	μA
I_{CC}	Maximum Quiescent Supply Current	Select and V_{IS} = V_{CC} or GND	1.65 to 4.5	±1.0	±2.0	μA
I_{CCV}	Maximum Quiescent Supply Current, Low Voltage Driving (Note 6)	V_{IS} = V_{CC} or GND V_{IN} = 1.65 V	4.3	±145	±150	μA
		V_{IS} = V_{CC} or GND V_{IN} = 1.80 V		±125	±130	
		V_{IS} = V_{CC} or GND V_{IN} = 2.60 V		±50	±55	

6. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

NLAS5223CL DC ELECTRICAL CHARACTERISTICS − ANALOG SECTION

Symbol	Parameter	Condition	V_{CC}	Guaranteed Maximum Limit				Unit
				25°C		−40°C to +85°C		
				Min	Max	Min	Max	
R_{ON}	NC/NO On−Resistance (Note 7)	V_{IN} = V_{IL} or V_{IN} = V_{IH} V_{IS} = GND to V_{CC} I_{COM} = 100 mA	3.0 4.3		0.4 0.35		0.5 0.4	Ω
R_{FLAT}	NC/NO On−Resistance Flatness (Notes 7 and 8)	I_{COM} = 100 mA V_{IS} = 0 to V_{CC}	3.0 4.3		0.16 0.11		0.20 0.14	Ω
ΔR_{ON}	On−Resistance Match Between Channels (Notes 7 and 9)	V_{IS} = 1.5 V; I_{COM} = 100 mA V_{IS} = 2.2 V; I_{COM} = 100 mA	3.0 4.3		0.05 0.05		0.05 0.05	Ω
$I_{NC(OFF)}$ $I_{NO(OFF)}$	NC or NO Off Leakage Current (Note 7)	V_{IN} = V_{IL} or V_{IH} V_{NO} or V_{NC} = 0.3 V V_{COM} = 4.0 V	4.3	−10	10	−100	100	nA
$I_{COM(ON)}$	COM ON Leakage Current (Note 7)	V_{IN} = V_{IL} or V_{IH} V_{NO} 0.3 V or 4.0 V with V_{NC} floating or V_{NC} 0.3 V or 4.0 V with V_{NO} floating V_{COM} = 0.3 V or 4.0 V	4.3	−10	10	−100	100	nA

7. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
8. Flatness is defined as the difference between the maximum and minimum value of On−resistance as measured over the specified analog signal ranges.
9. ΔR_{ON} = $R_{ON(MAX)}$ − $R_{ON(MIN)}$ between NC1 and NC2 or between NO1 and NO2.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

Symbol	Parameter	Test Conditions	V_{CC} (V)	V_{IS} (V)	Guaranteed Maximum Limit					Unit
					25°C			−40°C to +85°C		
					Min	Typ*	Max	Min	Max	
t_{ON}	Turn−On Time	R_L = 50 Ω, C_L = 35 pF (Figures 3 and 4)	2.3 − 4.5	1.5			50		60	ns
t_{OFF}	Turn−Off Time	R_L = 50 Ω, C_L = 35 pF (Figures 3 and 4)	2.3 − 4.5	1.5			30		40	ns
t_{BBM}	Minimum Break−Before−Make Time	V_{IS} = 3.0 R_L = 50 Ω, C_L = 35 pF (Figure 2)	3.0	1.5	2	15				ns

		Typical @ 25, V_{CC} = 3.6 V	
C_{IN}	Control Pin Input Capacitance	3.5	pF
$C_{NO/NC}$	NO, NC Port Capacitance	60	pF
C_{COM}	COM Port Capacitance When Switch is Enabled	200	pF

*Typical Characteristics are at 25°C.

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

Symbol	Parameter	Condition	V_{CC} (V)	25°C	Unit
				Typical	
BW	Maximum On−Channel −3 dB Bandwidth or Minimum Frequency Response	V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 − 4.5	24	MHz
V_{ONL}	Maximum Feed−through On Loss	V_{IN} = 0 dBm @ 100 kHz to 50 MHz V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 − 4.5	−0.06	dB
V_{ISO}	Off−Channel Isolation	f = 100 kHz; V_{IS} = 1 V RMS; C_L = 5.0 pF V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 − 4.5	−68	dB
Q	Charge Injection Select Input to Common I/O	V_{IN} = $V_{CC\ to}$ GND, R_{IS} = 0 Ω, C_L = 1.0 nF Q = C_L x DV_{OUT} (Figure 6)	1.65 − 4.5	38	pC
THD	Total Harmonic Distortion THD + Noise	F_{IS} = 20 Hz to 20 kHz, R_L = R_{gen} = 600 Ω, C_L = 50 pF V_{IS} = 2.0 V RMS	3.0	0.08	%
VCT	Channel−to−Channel Crosstalk	f = 100 kHz; V_{IS} = 1.0 V RMS, C_L = 5.0 pF, R_L = 50 Ω V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 − 4.5	−70	dB

10. Off−Channel Isolation = 20log10 (V_{COM}/V_{NO}), V_{COM} = output, V_{NO} = input to off switch.

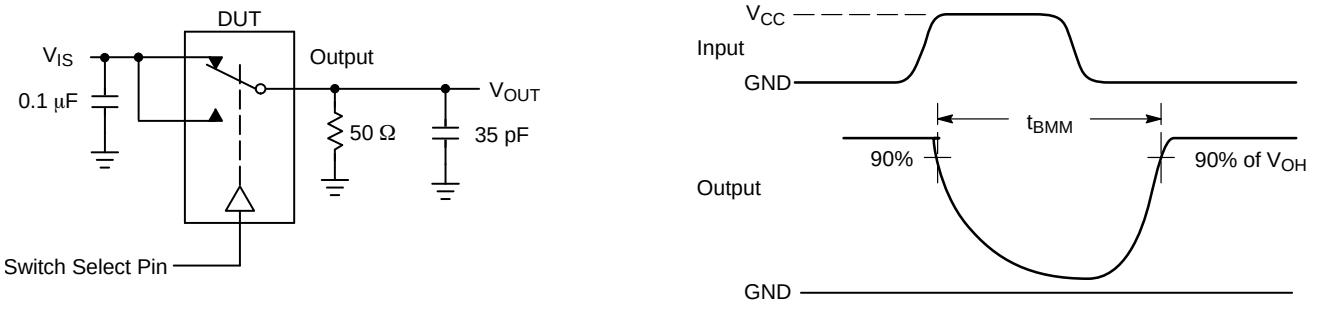


Figure 2. t_{BBM} (Time Break−Before−Make)

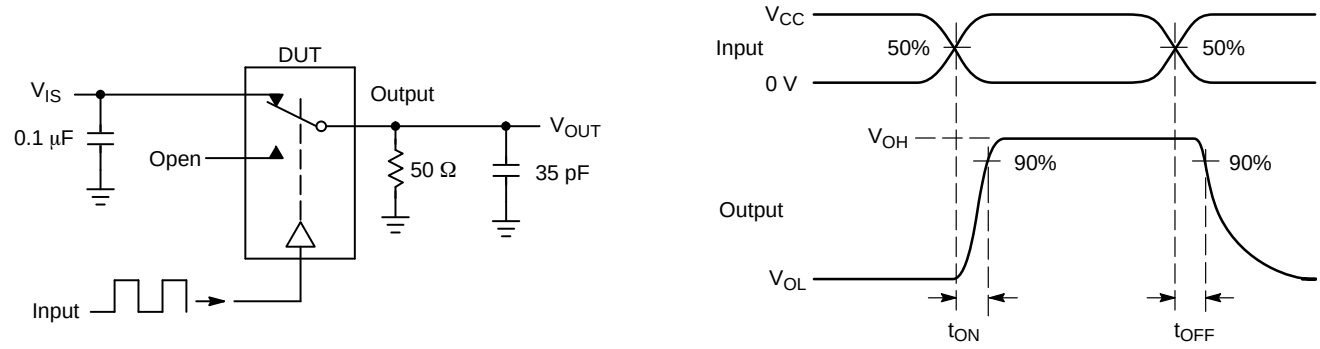


Figure 3. t_{ON}/t_{OFF}

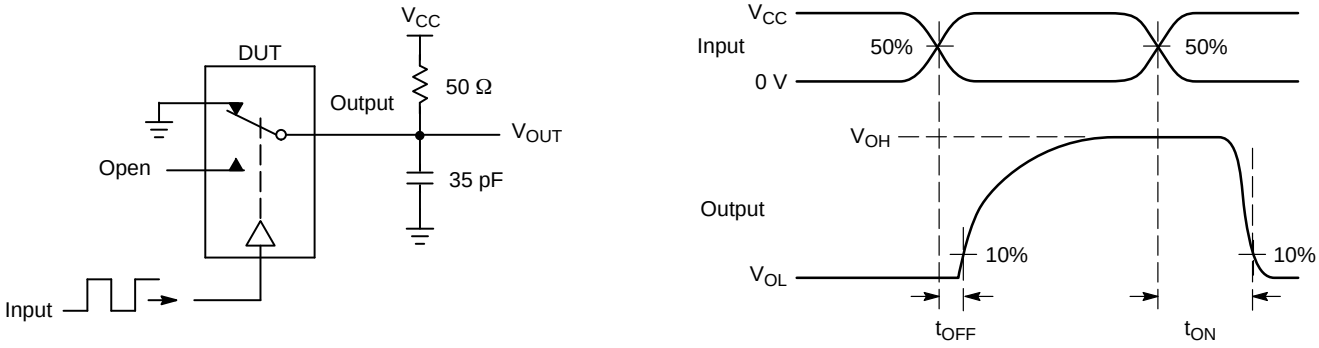
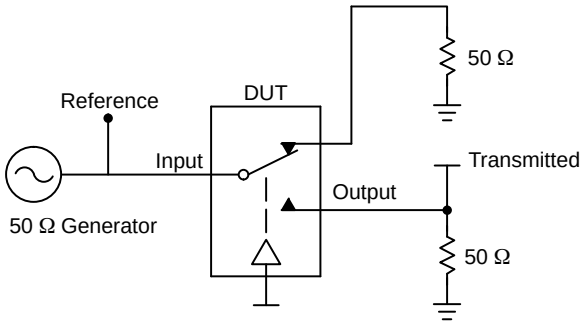


Figure 4. t_{ON}/t_{OFF}



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO}, Bandwidth and V_{ONL} are independent of the input signal direction.

V_{ISO} = Off Channel Isolation = $20\ \text{Log}\left(\frac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz

V_{ONL} = On Channel Loss = $20\ \text{Log}\left(\frac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz to 50 MHz

Bandwidth (BW) = the frequency 3 dB below V_{ONL}
V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω

Figure 5. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V_{ONL}

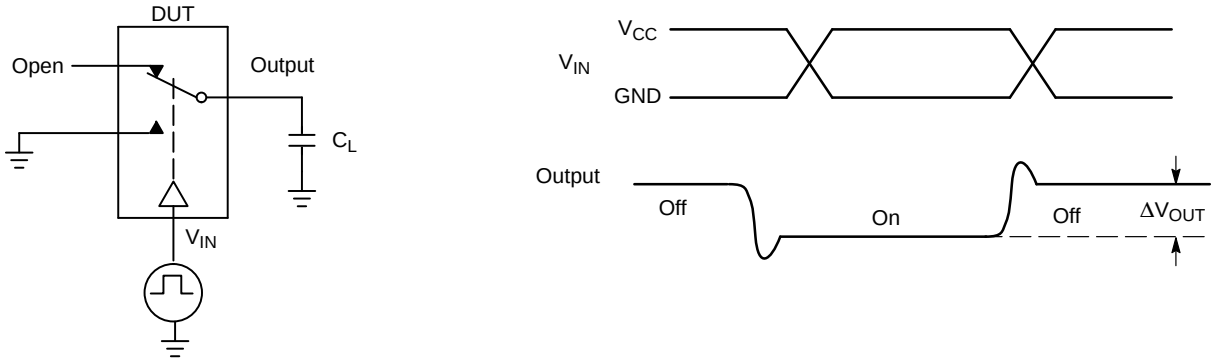


Figure 6. Charge Injection: (Q)

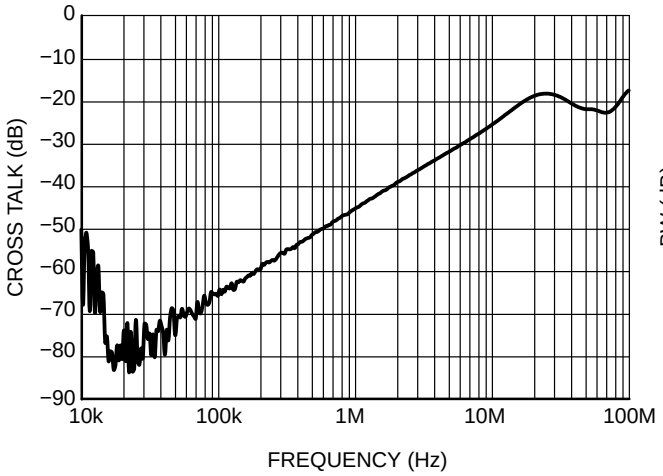


Figure 7. Cross Talk vs. Frequency (V_{CC} = 3.0 V)

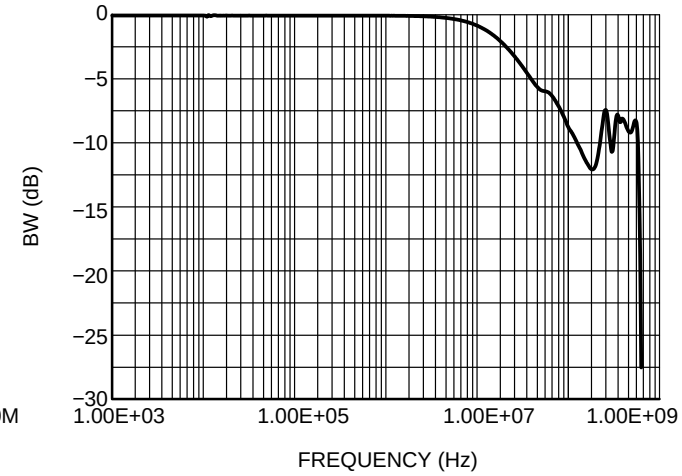


Figure 8. Bandwidth (V_{CC} = 3.0 V)

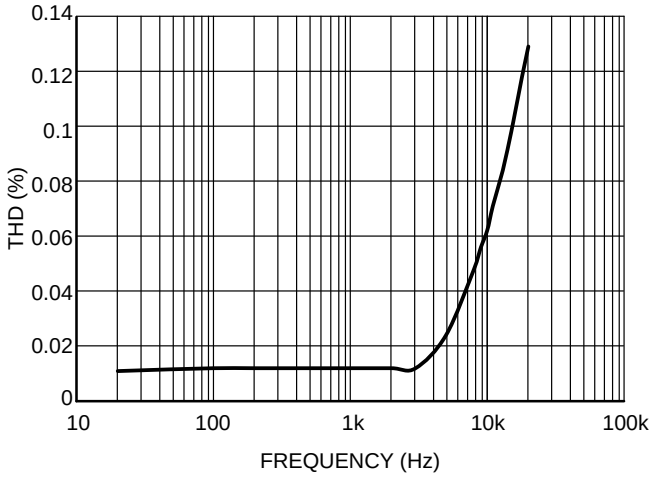


Figure 9. Total Harmonic Distortion (V_{CC} = 3.0 V)

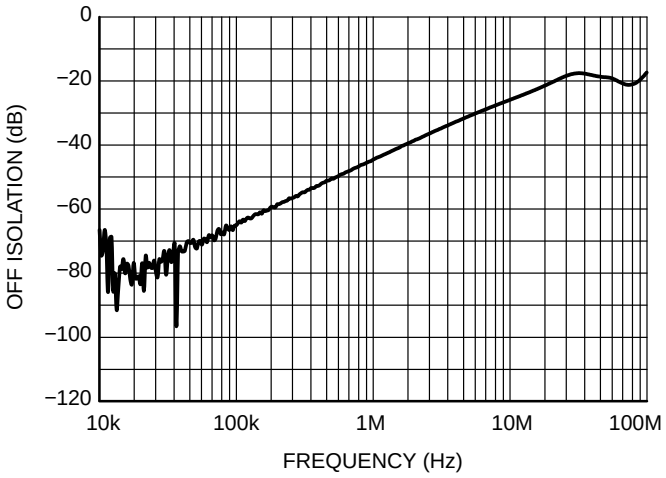


Figure 10. Off Isolation (V_{CC} = 3.0 V)

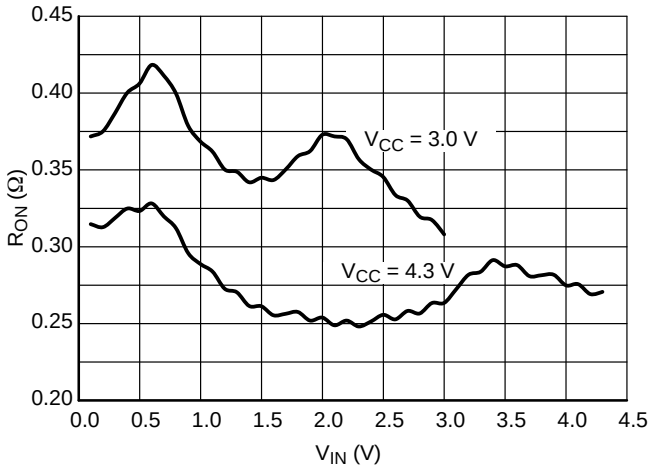


Figure 11. On−Resistance vs. Input Voltage @ 25°C and V_{CC} = 3.0 V and 4.3 V

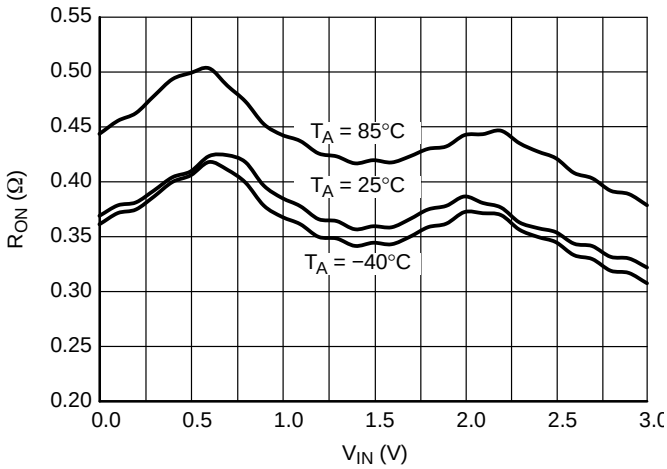


Figure 12. On−Resistance vs. Input Voltage @ V_{CC} = 3.0 V, T_A = −40°C to 85°C

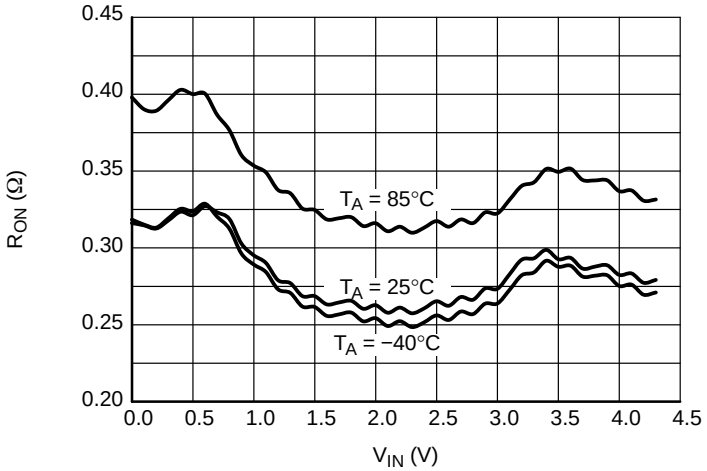


Figure 13. On−Resistance vs. Input Voltage @ V_{CC} = 3.0 V, T_A = −40°C to 85°C

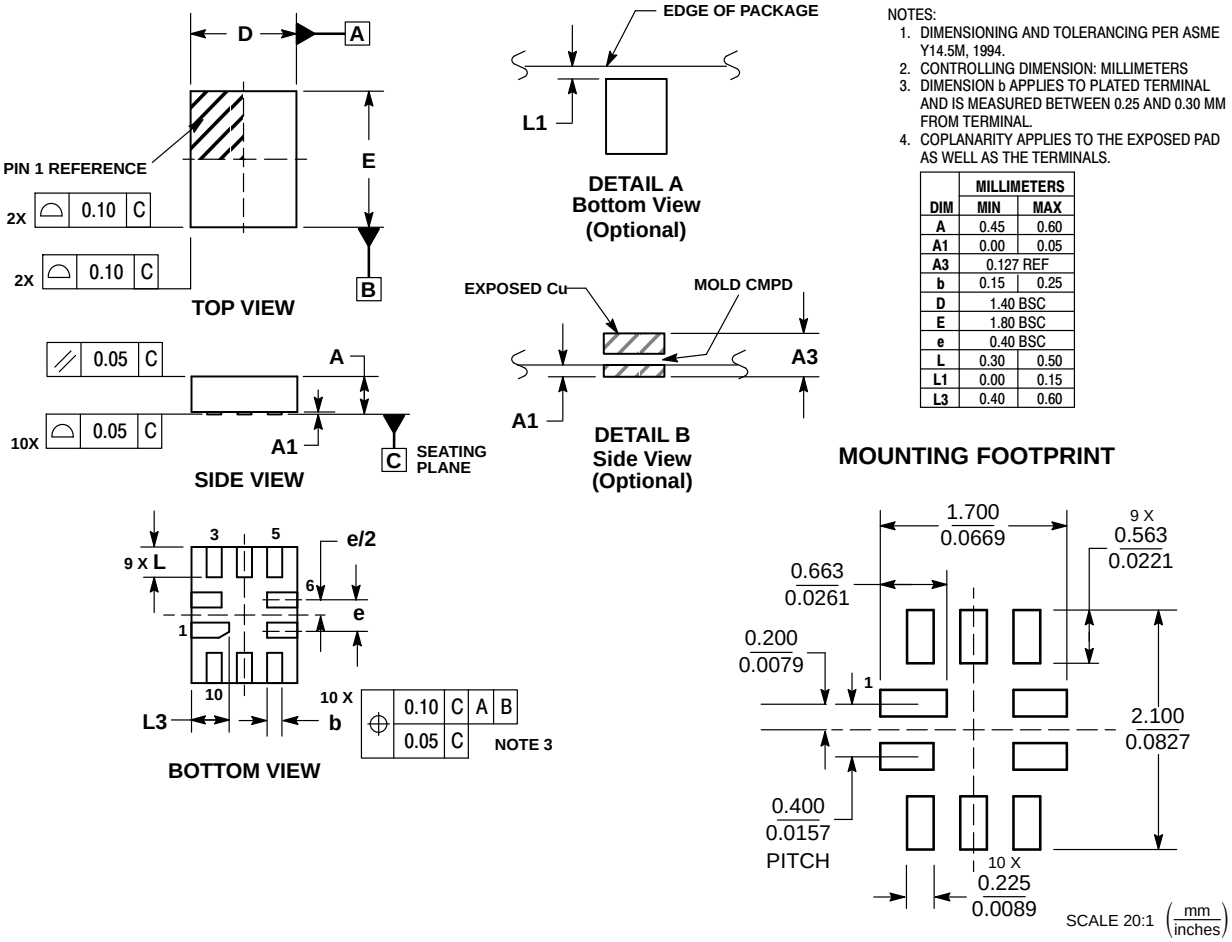
ORDERING INFORMATION

Device	Marking	Package	Shipping†
NLAS5223CMUTAG	AK	UQFN10 (Pb−Free)	3000 / Tape & Reel
NLAS5223CLMUTAG	AU	UQFN10 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

UQFN10, 1.4x1.8, 0.4P
CASE 488AT
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
A	0.45	0.60
A1	0.00	0.05
A3	0.127 REF	
b	0.15	0.25
D	1.40 BSC	
E	1.80 BSC	
e	0.40 BSC	
L	0.30	0.50
L1	0.00	0.15
L3	0.40	0.60

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
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Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

NLAS5223C/D

OCEAN CHIPS
Океан Электроники
Поставка электронных компонентов

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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AVIC JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

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